# <u>Session 6</u>: *Spintronics and Magneto Electronics* by Sergio Valenzuela, Barcelona

Raporteur: Christian Pithan, FZJ – PGI, Jülich

#### Comprehensive overview on spingtronics related to

- 1.) Current technologies and developments (GMR, TMR, MRAM)
- 2.) New fundamental physical phenomena and potentially emerging applications (Transfer between pure scientific and application side is an important issue)

### Charge transport vs. spin dynamics

Spintronics opens possibilities for nonvolatile and low dissipation memory devices (Spins do not need to be in motion for information transport)

# Vision based on experimental and theoretical observations of the recent past Pure spin currents without charge transfer in integrated circuits and quantum manipulation / coupling of spin states.

- At present: controlled by magnetic field or spin-polarized charge currents
- Future: controlled by electric field and no charge currents

### Giant Magnetoresistance (GMR), Tunnel Magnetoresistance (TMR)

- Parallel allignment  $\rightarrow$  transmission, Antiparallel allignment  $\rightarrow$  no transmission
- Commercialization (Grünberg -patent): Magnetic sensors and data storage
- Magnetic Access Random Memory (MRAM)
  - At present: **Toogle RAM** with low leakage, reduced dissipation, fast writing/ reading but larger power requirements for writing, cell size to large

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### Magnetic Access Random Memory (MRAM)

- Curr. development: Spin transfer torque RAM (lithographically refined domains, reduced cell size)
  - Heat assisted switching RAM (TAS-MRAM) (writing at elevated temperatures)
  - Other torque/switching mechanisms (via electrical field, multiferroics ...)

# Race track memory concept

- Proposed by IBM
- Domain structure along a ferromagnetic line used to store information in a 3 dim. arrangement

# Intriguing new physical discoveries from which practical possibilities could emerge:

- RF-applications, spin logics, spin hall effect, spin Seebeck effect, Quantum computing ...
- Many encouring proposals, developments or reports from the scientific literature
- Often still new fundamental physics and a lot of new scientific work needed
- Real application sometimes unclear (e.g. spin Seebeck effect)

# Discussion with the discussant (Paolo Lugli) and the auditorium

- Level of maturity and impact in society ...
- Role of contacts and interconnects in spin based devices ...
- Reliability and stability issues ...
- Role of the superparamagnetic limit in the evolution of MRAM and spintronic in general ...
- Role of molecular spintronics or molecular magnets (example of Ferritin molecule) ...